

View Online at <https://aerobasegroup.com/nsn/5980-01-294-3236>

General Description:

Gallium arsenide diode light source is optically coupled to a silicon npn phototransistor; 2.0 vdc maximum on diode; 35.0 vdc on phototransistor; 6 leads; metal can pkg; 0.170 in. Lg; 0.335 in. Min to 0.370 in. Maximum dia; electrostatic sensitive; burn-in required; rescreened

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

A23900